Photocouplers Infrared LED & Photo IC

TLX9310

- Automotive
- Battery Management System (BMS)

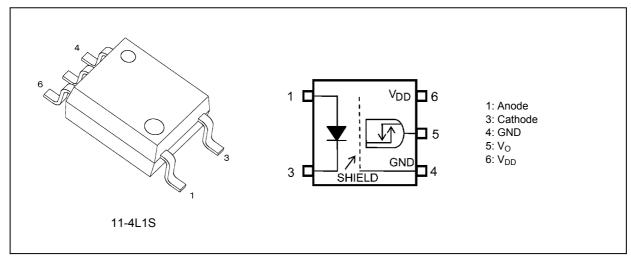
2. General

The Toshiba TLX9310 consists of a high-output an infrared LED coupled with a high-speed photo-diode-transistor chip. It is housed in the SO6 package. This photocoupler guarantees operation at up to 105 °C and on supplies from 2.7 V to 5.5 V. Since TLX9310 has guaranteed 0.3 mA low supply current (I_{DDL}/I_{DDH}), and 1.0 mA ($T_{opr} = 105$ °C) low threshold input current(I_{FHL}), it contributes to energy saving of devices. It can drive directly from a microcomputer for a low input current.

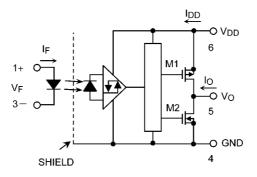
3. Features

- (1) Buffer logic type (totem pole output)
- (2) Package: SO6
- (3) Operating temperature: -40 to 105 °C
- (4) Supply voltage: 2.7 to 5.5 V
- (5) Threshold input current: 1.0 mA (max)
- (6) Supply current: 0.3 mA (max)
- (7) Data transfer rate: 5 Mbps (typ.)
- (8) Common-mode transient immunity: $\pm 25 \text{ kV/}\mu s$ (min)
- (9) Isolation voltage: 3750 Vrms (min)
- (10) AEC-Q101 qualified

4. Packaging and Pin Assignment



5. Internal Circuit (Note)



Note: A $0.1-\mu F$ bypass capacitor must be connected between pin 6 and pin 4.

6. Principle of Operation

6.1. Truth Table

Input	LED	Output
Н	ON	Н
L	OFF	L

6.2. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	5.0	mm
Clearance	5.0	
Internal isolation thickness	_	

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25 \text{ °C}$)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		١ _F		8	mA
	Input forward current derating (T _a ≥ 85 °C)	$\Delta I_F / \Delta T_a$		-0.05	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	1	А
	Input power dissipation		PD		20	mW
	Input reverse voltage		V _R		5	V
Detector	Output current		Ι _Ο		10	mA
	Output voltage		Vo		6	V
	Supply voltage		V _{DD}		6	V
	Output power dissipation		Po		20	mW
Common	Operating temperature		T _{opr}		-40 to 105	°C
	Storage temperature		T _{stg}		-55 to 125	°C
	Lead soldering temperature	(10 s)	T _{sol}		260	°C
	Isolation voltage (AC, 6	0 s, R.H. ≤ 60 %)	BVS	(Note 2)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 1 μ s, 300 pps

Note 2: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V_{DD}		2.7	3.0 to 5.0	5.5	V
Operating temperature	T _{opr}		-40	_	105	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note: A ceramic capacitor $(0.1 \,\mu\text{F})$ should be connected between pin 6 (V_{DD}) and pin 4 (GND) to stabilize the operation of a high-gain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note: If the rising slope of the supply voltage (V_{DD}) for the detector is steep, stable operation of the internal circuits cannot be guaranteed.

Be sure to set 3.0 V/ μs or less for a rising slope of the V_DD.

9. Electrical Characteristics (Note) (Unless otherwise specified, T_a = -40 to 105 °C, V_{DD} = 2.7 to 5.5 V)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V _F		I _F = 2 mA, T _a = 25 °C	1.4	1.55	1.7	V
			I _F = 2 mA	1.2	_	1.9	
Input reverse current	I _R		V _R = 5 V, T _a = 25 °C	_	_	10	μΑ
Input capacitance	Ct		V = 0 V, f = 1 MHz , T _a = 25 °C	-	20	—	pF
Low-level output voltage	V _{OL}	Fig. 12.1	I _F = 0 mA, I _O = 20 μA	_	_	0.1	V
			I _F = 0 mA, I _O = 3.2 mA	_	_	0.4	
High-level output voltage	V _{OH}	Fig. 12.2	I _F = 2 mA, I _O = -20 μA	V _{DD} -0.1	_	_	V
			I _F = 2 mA, I _O = -3.2 mA	V _{DD} -1.0			
Low-level supply current	I _{DDL}	Fig. 12.3	I _F = 0 mA	_	_	0.3	mA
High-level supply current	I _{DDH}	Fig. 12.4	I _F = 2 mA	_	_	0.3	mA
Threshold input current (L/H)	I _{FLH}		I _O = -3.2 mA, V _O > 2.4 V	—		1.0	mA

Note: All typical values are at V_{DD} = 5 V, T_a = 25 °C, unless otherwise noted.

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	CS	(Note 1)	V _S = 0 V, f = 1 MHz	—	0.8	_	pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. \leq 60 %	10 ¹²	10 ¹⁴	—	Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	3750	_	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

11. Switching Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 105 °C, $V_{DD} = 2.7$ to 5.5 V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (L/H)	t _{pLH}	(Note 1)	Fig.12.5	V _{IN} = 3.3 V, R _T = 820 Ω	_	_	250	ns
Propagation delay time (H/L)	t _{pHL}				—	_	250	
Pulse width distortion	t _{pHL} -t _{pLH}				_	_	50	
Propagation delay skew (device to device)	t _{psk}	(Note 1), (Note 2)			_	_	65	
Propagation delay time (L/H)	t _{pLH}	(Note 1)	Fig.12.5	V _{IN} = 5 V, R _T = 1.6 kΩ	_	_	250	ns
Propagation delay time (H/L)	t _{pHL}				_	_	250	
Pulse width distortion	t _{pHL} -t _{pLH}				_	_	50	
Propagation delay skew (device to device)	t _{psk}	(Note 1), (Note 2)			_	_	65	
Rise time	t _r	(Note 1)	Fig.12.5			11	—	ns
Fall time	t _f				_	13	—	
High-level common-mode transient immunity	CM _H		Fig.12.6	V _{IN} = 3.3 V/5 V, V _{DD} = 2.7 V/5 V,	±25	±40	—	kV/μs
Low-level common-mode transient immunity	CML			V _{CM} = 1000 V _{p-p} , T _a = 25 °C				

Note: All typical values are at V_{DD} = 5 V, T_a = 25 °C, unless otherwise noted.

Note: Recommendation input resistance conditions

 \cdot V_{IN} = 3.3 V: R₁ = R₂ = 430 Ω

Note 1: f = 250 kHz, duty = 50 %, input current $t_r = t_f = 5$ ns, C_L is less than 15 pF which includes probe and stray wiring capacitance.

Note 2: The propagation delay skew, t_{psk}, is equal to the magnitude of the worst-case difference in t_{pHL} and/or t_{pLH} that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc.).

12. Test Circuits

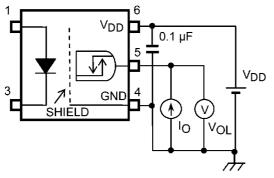


Fig. 12.1 V_{OL} Test Circuit

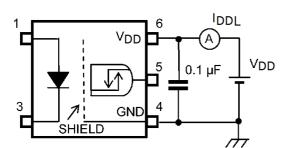


Fig. 12.3 IDDL Test Circuit

V_{IN} = 3.3 V / 5 V (P.G.)

(f = 250 kHz, duty = 50 %, less than $t_r = t_f = 5 \text{ ns}$)

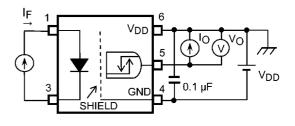


Fig. 12.2 V_{OH} Test Circuit

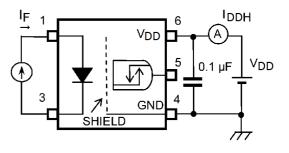


Fig. 12.4 IDDH Test Circuit

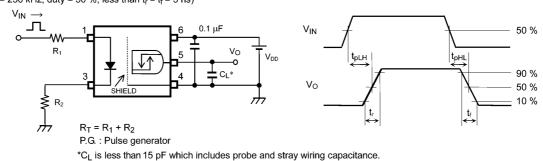
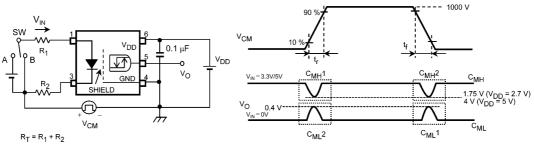
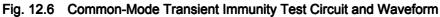


Fig. 12.5 Switching Time Test Circuit and Waveform

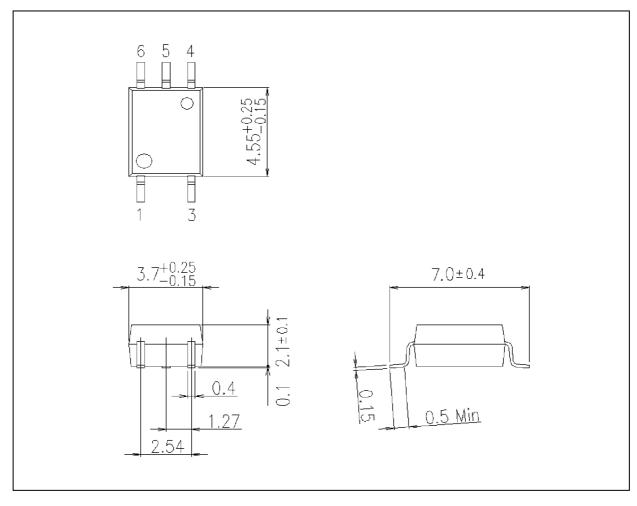




Package Dimensions

Unit: mm

TLX9310



Weight: 0.08 g (typ.)

Package Name(s)

TOSHIBA: 11-4L1S

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